Features

- **Programmable DMUX Ratio:**
    - **1:4: Data Rate Max = 1 Gsps**
    - **PD (8b/10b) < 4.3/4.7 W (ECL 50Ω output)**
    - **1:8: Data Rate Max = 2 Gsps**
    - **PD (8b/10b) < 6/6.9 W (ECL 50Ω output)**
    - **1:16 with 1 TS8388B or 1 TS83102G0B and 2 DMUX**
- **Parallel Output Mode**
- **8-/10-bit**
- **ECL Differential Input Data**
- **DataReady or DataReady/2 Input Clock**
- **Input Clock Sampling Delay Adjust**
- **Single-ended Output Data:**
    - **Adjustable Common Mode and Swing**
    - **Logic Threshold Reference Output**
    - **(ECL, PECL, TTL)**
- **Asynchronous Reset**
- **Synchronous Reset**
- **ADC + DMUX Multi-channel Applications:**
    - **Stand-alone Delay Adjust Cell for ADCs Sampling Instant Alignment**
- **Differential Data Ready Output**
- **Built-in Self Test (BIST)**
- **Dual Power Supply V_{EE} = -5V, V_{CC} = +5V**
- **Radiation Tolerance Oriented Design (More than 100 Krad (Si) Expected)**
- **TBGA 240 (Cavity Down) Package**

Description

The TS81102G0 is a monolithic 10-bit high-speed (up to 2 GHz) demultiplexor, designed to run with all kinds of ADCs and more specifically with Atmel's high-speed ADC 8-bit 1 Gsps TS8388B and ADC 10-bit 2 Gsps TS83102G0B.

The TS81102G0 uses an innovative architecture, including a sampling delay adjust and tunable output levels. It allows users to process the high-speed output data stream down to processor speed and uses the very high-speed bipolar technology (25 GHz NPN cut-off frequency).
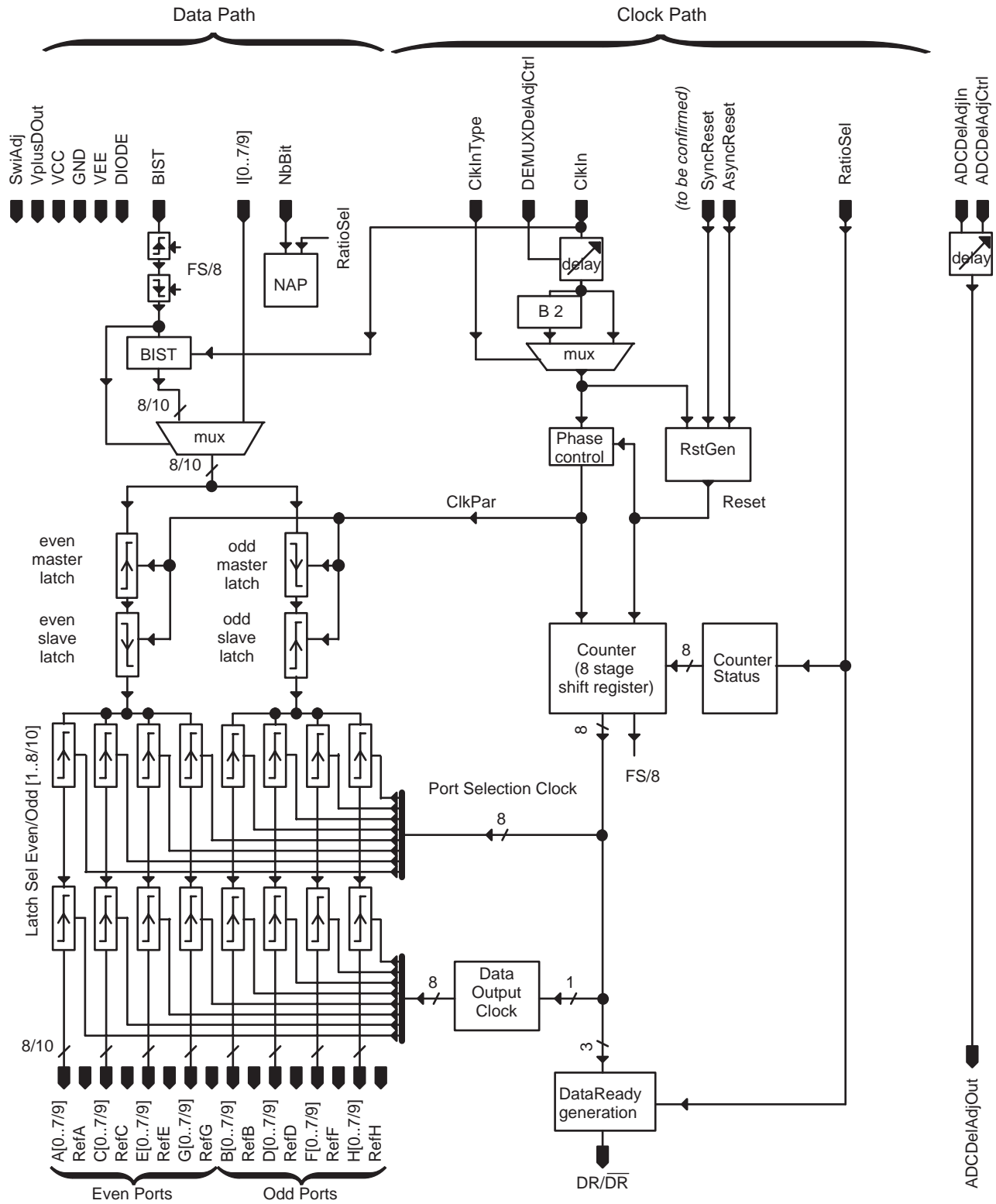
DMUX 8-/10-bit 2 GHz 1:4/8
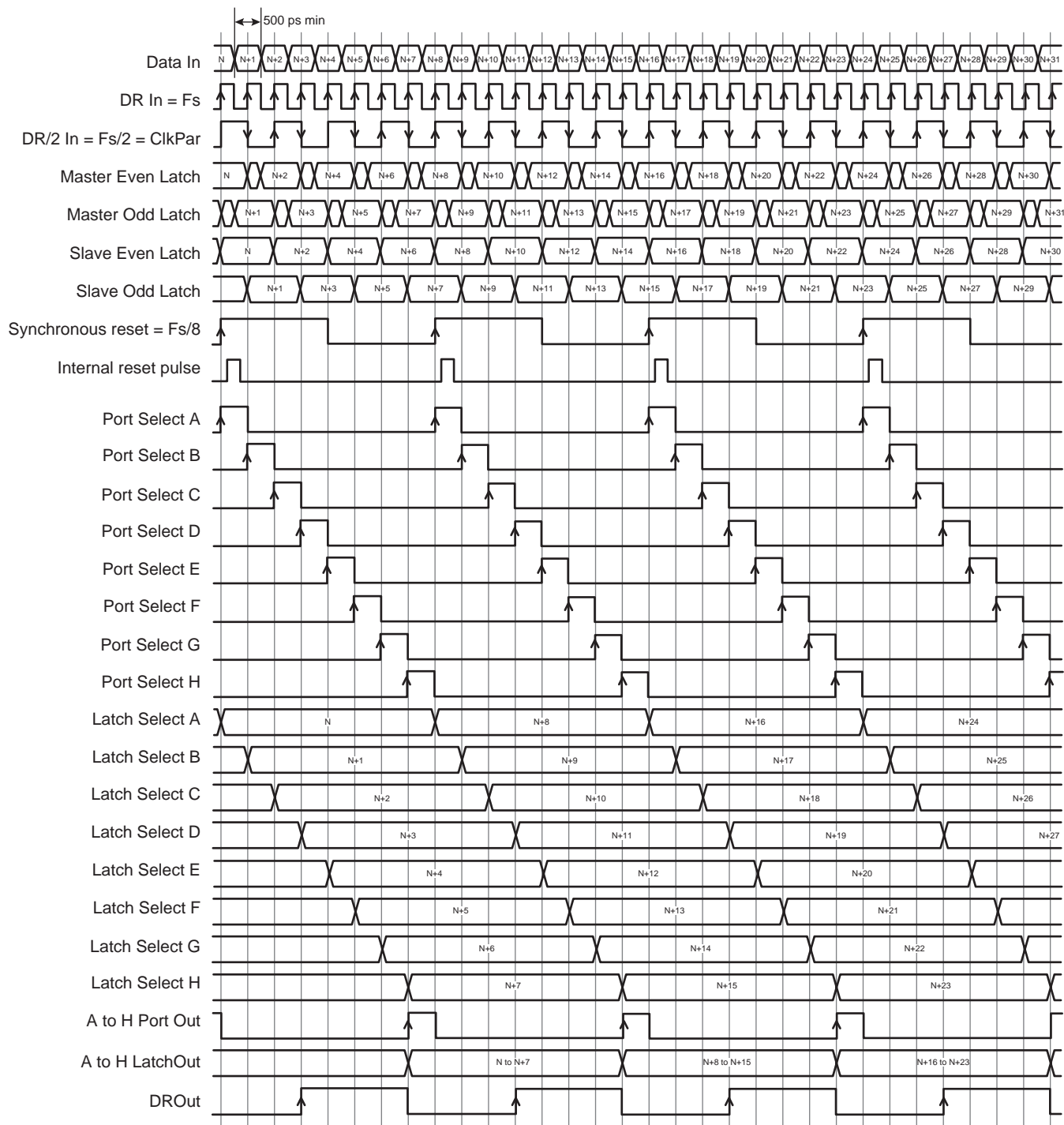
TS81102G0

Block Diagram

Figure 1. Block Diagram

Internal Timing Diagram

This diagram corresponds to an established operation of the DMUX with Synchronous Reset.

Figure 2. Internal Timing Diagram

Functional Description

The TS81102G0 is a demultiplexer based on an advanced high-speed bipolar technology featuring a cutoff frequency of 25 GHz. Its role is to reduce the data rate so that the data can be processed at the DMUX output.

The TS81102G0 provides 2 programmable ratios: 1:4 and 1:8. The maximum data rate is 1 Gsps for the 1:4 ratio and 2 Gsps for the 1:8 ratio.

The TS81102G0 is able to process 8 or 10-bit data flows.

The input clock can be an ECL differential signal or single-ended DC coupled signal. Moreover it can be a DataReady or DataReady/2 clock.

The input digital data must be an ECL differential signal.

The output signals (Data Ready, digital data and reference voltage) are adjustable with VplusD independent power supply. Typical output modes are ECL, PECL or TTL.

The Data Ready output is a differential signal. The digital output data and reference voltages are single-ended signals.

The TS81102G0 is started by an Asynchronous Reset. A Synchronous Reset enables the user to re-synchronize the output port selection and to minimize loss of data that could occur within the DMUX.

A delay adjust cell is available to ensure a good phase between the DMUX' input clock and input data.

Another delay adjust cell is available to control the ADCss sampling instant alignment, in case of the ADCs interleaving.

A 10-bit generator is implemented in the TS81102G0, the Built-In Self Test (BIST). This test sequence is very useful for testing the DMUX at first use.

A fine tuning of the output swing is also available.
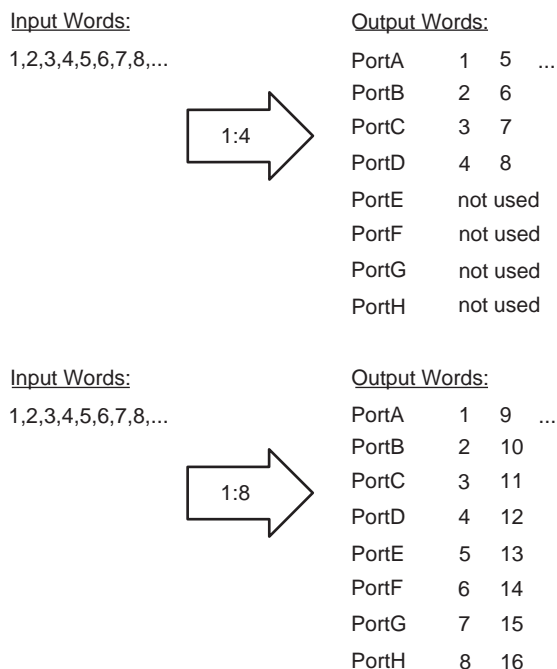
The TS81102G0 can be used with the following Atmel ADCs:
- TS8388B(F/FS/GL), 8-bit 1 Gsps ADC
- TS83102G0B, 10-bit 2 Gsps ADC

Main Function Description
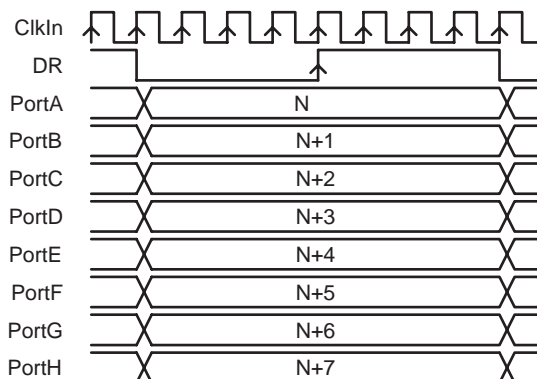
Programmable DMUX Ratio

The conversion ratio is programmable: 1:4 or 1:8.

Figure 3. Programmable DMUX Ratio

Input Words:		Output Words:			
1,2,3,4,5,6,7,8,...		PortA	1	5	...
		PortB	2	6	
	1:4	PortC	3	7	
		PortD	4	8	
		PortE	not used		
		PortF	not used		
		PortG	not used		
		PortH	not used		

Input Words:		Output Words:			
1,2,3,4,5,6,7,8,...		PortA	1	9	...
		PortB	2	10	
		PortC	3	11	
	1:8	PortD	4	12	
		PortE	5	13	
		PortF	6	14	
		PortG	7	15	
		PortH	8	16	

Parallel Output Mode
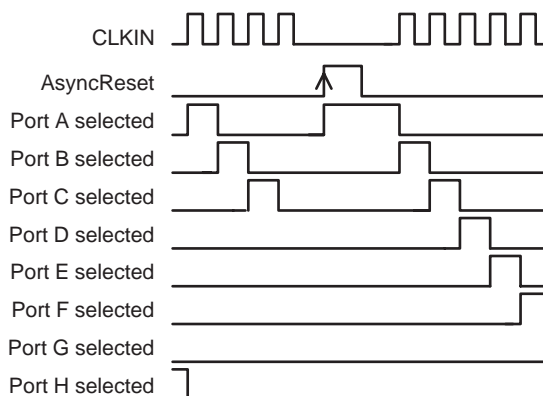
Figure 4. Parallel Mode

Input Clock Sampling Delay Adjust (DEMUXDELADJCTRL)

The input clock phase can be adjusted with an adjustable delay (from 250 to 750 ps). This is to ensure a proper phase between the clock and input data of the DMUX.

Asynchronous Reset (ASYNCRESET)
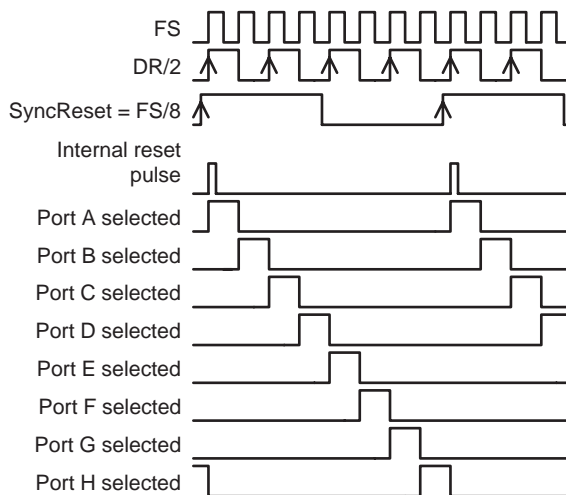
Figure 5. Asynchronous Reset

The Asynchronous Reset is a master reset of the port selection, which works on TTL levels. It is active on the high level. During an asynchronous reset, the clock must be in a known state. It is used to start the DMUX.

When it is active, it paralyzes the outputs (the output clock and output data remain at the same level as before the asynchronous reset). When it comes back to its low level, the DMUX starts: the outputs are active and the first processed data is on port A.

Synchronous Reset (SYNCRESET)

Figure 6. Synchronous Reset

The DMUX can be synchronously reset to a programmable state depending on the conversion ratio. The clock must not be stopped during reset. The synchronization signal is a clock (SyncRest) whose frequency is FS/8*n where n is an integer (n = 1,2,3,…) in 1:8 mode and FS/4*n in 1:4 mode. The front edge of this clock is synchronized with Clkln inside the DMUX, and generates a 200 ps reset pulse. This reset pulse occurs during a fixed level of Clkln.

If the DMUX was synchronized with Syncreset previous to a possible loss of synchronization, then the output data is immediately correct, no modification can be seen at the output of the DMUX, and no data is lost ("Internal Timing Diagram" on page 3).

If the DMUX was not synchronized with SyncReset previous to a possible loss of synchronization, then the output data and data ready of the DMUX are changed. The output data is correct after a number of input clocks corresponding to the pipeline delay ("Timing Diagrams with Synchronous Reset" on page 19).

Counter Programmable State

When the counter is reset, its initial states depends on the conversion ratio:
- 1:8: counting on 8 bits,
- 1:4: counting on 4 bits.

Pipeline Delay

The maximum pipeline delay depends on the conversion ratio:
- 1:8: pipeline delay = 7
- 1:4: pipeline delay = 3

8-/10-bit, with NAP Mode for the 2 Unused Bit

The DMUX is a 10-bit parallel device. The last two bits (bits 8 and 9) may not be used, and the corresponding functions are set to nap mode to reduce power consumption.
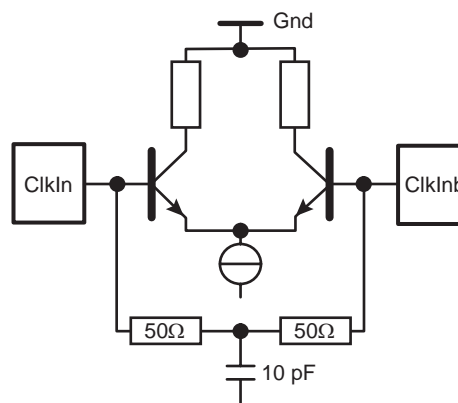
ECL Differential Input Data

Input data are ECL compatible (Voh = -0.8V, Vol = -1.8V).

The minimum swing required is 100 mV differential.

All inputs have a 100Ω differential termination resistor. The middle point of these resistors is connected to ground through a 10 pF capacitor.
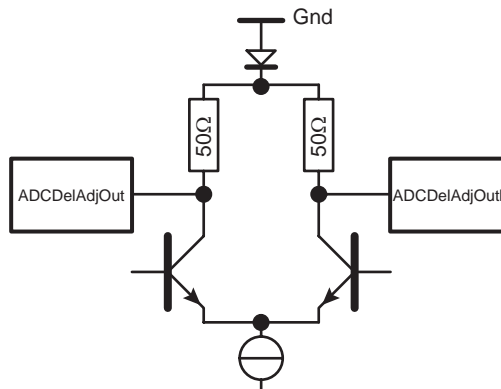
Figure 7. ECL Differential Input Data

50Ω Differential Output Data

The output clock for the ADC is generated through a 50Ω loaded long tailed. The 50Ω resistor is connected to the ground pad via a diode. The levels are (on the 100Ω differential termination resistor): Vol = -1.4V, Voh = -1.0V.

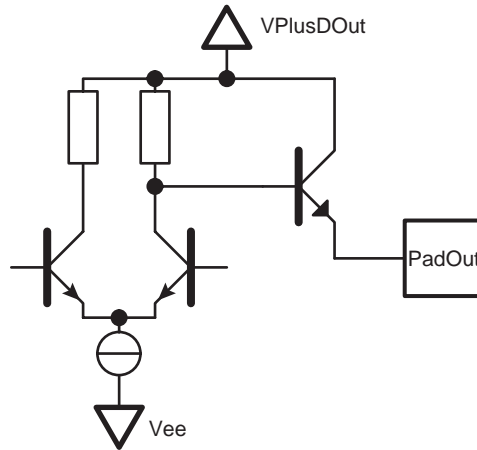**Figure 8.** 50Ω Differential Output Data

Single-ended Output Data

To reduce the pin number and power consumption of the DMUX, the eight output ports are single-ended.

To reach the high frequency output (up to 250 MHz) with a reasonable power consumption, the swing must be limited to a maximum of ±500 mV. The common mode is adjustable from -1.3V to +2V, with Vplus DOut pins. To ensure better noise immunity, a reference level (common mode) is available (one level by output port).

The output buffers are of ECL type (open emitters – not resistive adapted impedances). They are designed for a 15 mA average output current, and may be used with a 50Ω termination impedance.

Figure 9. Single-ended Output Data

Following are three application examples for these buffers: ECL/PECL/TTL. Please note that it is possible to have any other odd output format as far as current (36 mA max) and voltage (Vplus Dout – $V_{EE} \leq 8.3V$) limits are not overridden. The maximum frequency in TTL output mode depends on the load to be driven.

Table 1. Examples of Application of Buffers

Parameter	ECL	PECL	TTL	Unit
VplusDout	0	3.3	3.3	V
Vtt	-2	1.3	0	V
Swing	±0.5	±0.5	±1	V
Reference	-1.3	2	1.5	V
Voh	-0.8	2.5	2.5	V
Vol	-1.8	1.5	0.5	V
Load	50	50	≥75	Ω
Average Output Current	14	14	15	mA
Output Data rate max.	250	250	250	Msps

This corresponds to the "Adjustable Logic Single" in the pinout description.

The "Adjustable Single" buffers for reference voltage are the same buffers, but the information available at the output of these buffers is more like analog than logic.

Note: The Max Output Data Rate is given for a typical 50Ω/2 pF load.

Differential Data Ready Output

The front edge of the DataReady output occurs when data is available on the corresponding port. The frequency of this clock depends on the conversion ratio (1:8 or 1:4), with a duty cycle of 50%.

The definition is the same as for single-ended output data, but the buffers are differential.

This corresponds to the "Adjustable Logic Differential" in the pinout description.

Built-in Self Test (BIST)

A pseudo-random 10-bit generator is implemented in the DMUX. It generates a 10-bit signal in the output of the DMUX, with a period of 512 input clocks. The probability of occurrence of codes is uniformly spread over the 1024 possible codes: 0 or 1/1024.

Note that the 256 codes of bits 1 to 8 occur at least once. They start with a BIST command, in phase with the FS/8 clock on Port A. The logic output obtained on the A to H ports depends on the conversion ratio. The driving clock of BIST is ClkIn. The ClkInType must be set to '1' (DataReady ADC clock) to have a different 10-bit code on each output.

The complete BIST sequence is available on request.

Specifications

Absolute Maximum Ratings

Table 2. Absolute Maximum Ratings

Parameter	Symbol	Comments	Value	Unit
Positive supply voltage	V_{CC}		GND to 6	V
Positive output buffer supply voltage	V_{PLUSD}		GND to 4	V
Negative supply voltage	V_{EE}		GND to -6	V
Analog input voltages	ADCDelAdjCtrl, ADCDelAdjCtrlb or DMUXDelAdjCtrl, DMUXDelAdjCtrlb or SwiAdj	Voltage range for each pad / Differential voltage range	-1 to +1 / -1 to +1	V
ECL 50Ω input voltage	ClkIn or ClkInb or I[0…9] or I[0…9]b or SyncReset or SyncResetb or ADCDelAdjIn or ADCDelAdjInb	Voltage range for each pad	-2.2 to +0.6	V
Maximum difference between ECL 50Ω input voltages	ClkIn – ClkInb or I[0…9] - I[0…9]b or SyncReset – Syncresetb or ADCDelAdjIn - ADCDelAdjInb	Minimum differential swing / Maximum differential swing	0.1 / 2	V

Table 2. Absolute Maximum Ratings (Continued)

Parameter	Symbol	Comments	Value	Unit
Data output current	A[0…9] to H[0…9] or RefA to RefH or DR or DRb	Maximum current	36	mA
TTL input voltage	ClkIn Type RatioSel NbBit AsyncReset BIST		GND to V_{CC}	V
Maximum input voltage on diode for temperature measurement	DIODE		700	mV
Maximum input current on diode	DIODE		8	mA
Maximum junction temperature	T_j		135	°C
Storage temperature	T_{stg}		-65 to 150	°C

Note: Absolute maximum ratings are limiting values, to be applied individually, while other parameters are within specified operating conditions. Long exposure to maximum rating may affect device reliability. The use of a thermal heat sink is mandatory. See "Thermal and Moisture Characteristics" on page 26.

Recommended Operating Conditions

Table 3. Recommended Operating Conditions

Parameter	Symbol	Comments	Recommended Value			Unit
			Min	Typ	Max	
Positive supply voltage	V_{CC}		4.45	5	5.25	V
Positive output buffer supply voltage	V_{PLUSD}	ECL output compatibility	–	0	–	V
Positive output buffer supply voltage	V_{PLUSD}	PECL output compatibility	–	3.3	–	V
Positive output buffer supply voltage	V_{PLUSD}	TTL output compatibility	–	3.3	–	V
Negative supply voltage	V_{EE}		-5.25	-5	-4.75	V
Operating temperature range	T_J	Commercial grade: "C" Industrial grade: "V"	0 < Tc; Tj < 90 -40 < Tc; Tj < 110			°C

Electrical Operating Characteristics

Tj (typical) = 70°C. Full Temperature Range: -40°C < Tc; Tj < 110°C.

(Guaranteed temperature range are depending on part number)

Table 4. Electrical Specifications

Parameter	Symbol	Test Level	Value			Unit	Note
			Min	Typ	Max		
Power Requirements							
Positive supply voltage							
V_{CC}	V_{CC}		4.75	5	5.25	V	
$V_{PLUSDOUT}$	–		–	–	–	–	
ECL	V_{PLUSD}	1	-0.25	0	0.25	V	
PECL	V_{PLUSD}		3.135	3.3	3.465	V	
TTL	V_{PLUSD}		3.135	3.3	3.465	V	
Negative supply voltage							
V_{EE}	V_{EE}	1	-5.25	-5	-4.75	V	
Supply Currents							(1)
ECL (50Ω) and PECL (50Ω)							
V_{CC} (for every configuration)	I_{CC}		–	31	–	mA	
1:8, 8 bits	I_{PLUSD}		540	1180	1820	mA	
	I_{EE}		–	719	–	mA	
1:8, 10 bits	I_{PLUSD}		640	1140	2240	mA	
	I_{EE}	1	–	790	–	mA	
1:4, 8 bits	I_{PLUSD}		270	590	910	mA	
	I_{EE}		–	592	–	mA	
1:4, 10 bits	I_{PLUSD}		320	720	1120	mA	
	I_{EE}		–	634	–	mA	
TTL (75Ω)							
V_{CC} (for every configuration)	I_{CC}		–	31	–	mA	
1:8, 8 bits	I_{PLUSD}		760	1610	2440	mA	
	I_{EE}		–	872	–	mA	
1:8, 10 bits	I_{PLUSD}		900	1770	3010	mA	
	I_{EE}	1	–	980	–	mA	
1:4, 8 bits	I_{PLUSD}		380	810	1220	mA	
	I_{EE}		–	670	–	mA	
1:4, 10 bits	I_{PLUSD}		450	880	1510	mA	
	I_{EE}		–	729	–	mA	
Nominal power dissipation							(1)
ECL (50Ω)							
1:8, 8 bits	PD		5.2	5.6	6	W	
1:8, 10 bits	PD	1	5.9	6.4	6.9	W	
1:4, 8 bits	PD		3.9	4.1	4.3	W	
1:4, 10 bits	PD		4.2	4.5	4.7	W	

Table 4. Electrical Specifications (Continued)

Parameter	Symbol	Test Level	Value			Unit	Note
			Min	**Typ**	**Max**		
PECL (50Ω)							
1:8, 8 bits	PD		5.8	6.2	6.6	W	
1:8, 10 bits	PD	1	6.6	7.1	7.6	W	
1:4, 8 bits	PD		4.2	4.4	4.6	W	
1:4, 10 bits	PD		4.6	4.8	5.1	W	
TTL (75Ω)							
1:8, 8 bits	PD		6.8	7.3	7.7	W	
1:8, 10 bits	PD	1	7.8	8.4	9	W	
1:4, 8 bits	PD		4.7	4.9	5.1	W	
1:4, 10 bits	PD		5.2	5.5	5.8	W	
Delay Adjust Control							
DMUXDelAdjCtrl differential voltage	DDAC		–	–	–		
250 ps			–	-0.5	–	V	
500 ps		–	–	0	–	V	
750 ps			–	0.5	–	V	
Input current	IDDAC		–	–	–	mA	
ADCDelAdjCtrl differential voltage	ADAC		–	–	–		
250 ps			–	-0.5	–	V	
500 ps		–	–	0	–	V	
750 ps			–	0.5	–	V	
Input current	IADAC		–	–	–	mA	
Digital Outputs							
ECL Output (assuming V_{PLUSD} = 0V, SWIADJ = 0V, 50Ω termination resistor on board)							
Logic "0" voltage	V_{OL}	1	–	-2.12	–	V	
Logic "1" voltage	V_{OH}		–	-1.16	–	V	
Reference voltage	V_{REF}		–	-1.40	–	V	
PECL Output (assuming V_{PLUSD} = 3.3V, SWIADJ = 0V, 50Ω termination resistor on board)							
Logic "0" voltage	V_{OL}	1	–	1.27	–	V	
Logic "1" voltage	V_{OH}		–	2.44	–	V	
Reference voltage	V_{REF}		–	1.83	–	V	
TTL Output (assuming V_{PLUSD} = 3.3V, SWIADJ = 0V, 75Ω termination resistor on board)							
Logic "0" voltage	V_{OL}	1	–	0.9	–	V	
Logic "1" voltage	V_{OH}		–	2.31	–	V	
Reference voltage	V_{REF}		–	1.2	–	V	
Output level drift with temperature (data and DR outputs)	–	–	–	-1.3	–	mV/°C	

Table 4. Electrical Specifications (Continued)

Parameter	Symbol	Test Level	Value			Unit	Note
			Min	**Typ**	**Max**		
Output level drift with temperature (reference outputs)	–	1	–	-0.9	–	mV/°C	
Digital Inputs							

ECL Input Voltages
    Logic "0" voltage
    Logic "1" voltage
	V_{IL}
	V_{IH}
		1	–
			-1.1
				–
				–
					-1.4
					–
						V
						V	

TTL Input Voltages
    Logic "0" voltage
    Logic "1" voltage
	V_{IL}
	V_{IH}
		1	–
			2.0
				–
				–
					0.8
					–
						V
						V	

Note: 1. The supply current I_{PLUSD} and the power dissipation depend on the state of the output buffers:
- the minimum values correspond to all the output buffers at low level,
- the maximum values correspond to all the output buffers at high level,
- the typical values correspond to an equal sharing-out of the output buffers between high and low levels.

Switching Performance and Characteristics

50% clock duty cycle (CLKIN, CLKINB). Tj (typical) = 70°C.

Full temperature range: -40°C < Tc; Tj < 110°C.

(Guaranteed temperature ranges depend on the part number)

See Timing Diagrams Figure 10 on page 16 to Figure 19 on page 21.

Table 5. Switching Performances

Parameter	Symbol	Test Level	Value			Unit	Note
			Min	**Typ**	**Max**		
Input Clock							

Maximum clock frequency
    1:8 ratio
    1:4 ratio
	FMAX	–	2
			1
				–
				–
					2.2
					1.1
						GHz	

Clock pulse width (high)	TC1	–	100	–	–	ps	
Clock pulse width (low)	TC2	–	100	–	–	ps	

Clock Path pipeline delay
    DR input clock
    DR/2 input clock
	TCPD
	TCPD
		–	–
			–
				981
				1084
					–
					–
						ps
						ps
							(1)
							(2)

Clock rise/fall time	TRCKIN TFCKIN	–	–	100	–	ps	
Asynchronous Reset							
Asynchronous Reset pulse width	PWAR	–	1000	–	–	ps	
Setup time from Asynchronous to Clkln	TSAR	–	–	1500	–	ps	
Rise/fall time for (10% – 90%)	TRAR TFAR	–	1000	–	–	ps	

Table 5. Switching Performances (Continued)

Parameter	Symbol	Test Level	Value			Unit	Note
			Min	Typ	Max		
Synchronous Reset							

Setup time from SyncReset to ClkIn
   DR input clock
   DR/2 input clock
	TSSR	–
		
			–
			–
				-580
				-477
					–
					–
						ps
						ps
							(3)
							(4)

Hold time from ClkIn to SyncReset
   DR input clock
   DR/2 input clock
	THSR	–
		
			–
			–
				780
				677
					–
					–
						ps
						ps
							(5)
							(6)

Rise/fall for (10% – 90%)	TSRR/TFSR	–	100	–	–	ps	
Input Data							

Setup time from I[0…9] to ClkIn
   DR input clock
   DR/2 input clock
	TSCKIN	–
		
			–
			–
				-794
				-691
					–
					–
						ps
						ps
							(7)
							(8)

Hold time from ClkIn to I[0…9]
   DR input clock
   DR/2 input clock
	THCKIN	–
		
			–
			–
				994
				891
					–
					–
						ps
						ps
							(9)
							(10)

Rise/fall for (10% – 90%)	TRDI/TFDI	–	100	–	–	ps	
Output Data							

Data output delay
   DR input clock
   DR/2 input clock
	TOD	–
		
			–
			–
				1820
				1717
					–
					–
						ps
						ps
							(11)
							(12)

Data pipeline delay
   DR input clock, 1:4 ratio
   DR input clock, 1:8 ratio
   DR/2 input clock, 1:4 ratio
   DR/2 input clock, 1:8 ratio
	TPD	–
		
			–
			–
			–
			–
				3
				7
				3/2
				7/2
					–
					–
					–
					–
						Number of input clock	(13)

Rise/fall for (10% – 90%)	TROD/tfod	–	–	497/484	–	ps	(14)
Data Ready							

Data ready Falling edge
   DR input clock
   DR/2 input clock
	TDRF	–
		
			–
			–
				1856
				1753
					–
					–
						ps
						ps
							(15)
							(16)

Data ready Rising edge
   DR input clock
   DR/2 input clock
	TDRR	–
		
			–
			–
				1828
				1725
					–
					–
						ps
						ps
							(17)
							(18)

Asynchr; Reset to DataReady delay	TARDR	–	–	1918	–	ps	(19)
Synchr. Reset to DataReady delay	TSRDR	–	–	1037	–	ps	(20)
Rise/fall for (10% – 90%)	TRDR/TFDR	–	–	450	–	ps	(21)
Rising edge uncertainty	JITTER	–	–	62	–	ps	
Built-In Self Test							
Hold time from ClkIn to BIST	THBIST	–	–	–	–	ps	(22)

Table 5. Switching Performances (Continued)

Parameter	Symbol	Test Level	Value			Unit	Note
			Min	**Typ**	**Max**		
Setup time from Bist to Clkln	TSBIST	–	–	1000	–	ps	
Rise/fall time for (10% – 90%)	TRBIST/ TFBIST	–	1000	–	–	ps	
ADC Delay Adjust							
Input frequency	FMADA	–	2	–	2.2	GHz	
Input pulse width (high)	TC1ADA	–	90	–	–	ps	
Input pulse width (low)	TC2ADA	–	90	–	–	ps	
Input rise/fall time	TRIADA/ TFIADA	–	100 100	150 150	– –	ps	
Output rise/fall time	TROADA/ TFOADA	–	– –	145 104	– –	ps	(23)
Data output delay (typical delay adjust setting)	TADA	–	– –	784 896	– –	ps	(24) (25)
Output delay drift with temperature	TADAT	–	–	2.5	–	ps/°C	
Output delay uncertainly	JITADA	–	–	30	–	ps	

Notes:
1. TCPD is tuned with DMUXDelAdjCtrl: TCPD = 981 ± 250 ps.
2. TCPD is tuned with DMUXDelAdjCtrl: TCPD = 1084 ± 250 ps.
3. TSSR depends on DMUXDelAdjCtrl: TSSR = -580 ± 250 ps. TSSR < 0 because of Clock Path internal delay.
4. TSSR depends on DMUXDelAdjCtrl: TSSR = -477 ± 250 ps. TSSR < 0 because of Clock Path internal delay.
5. THSR depends on DMUXDelAdjCtrl: THSR = 780 ± 250 ps.
6. THSR depends on DMUXDelAdjCtrl: THSR = 677 ± 250 ps.
7. TSCKIN depends on DMUXDelAdjCtrl: TSCKIN = -794 ± 250 ps. TSCKIN < 0 because of Clock Path internal delay.
8. TSCKIN depends on DMUXDelAdjCtrl: TSCKIN = -691 ± 250 ps. TSCKIN < 0 because of Clock Path internal delay.
9. THCKIN depends on DMUXDelAdjCtrl: THCKIN = 994 ± 250 ps.
10. THCKIN depends on DMUXDelAdjCtrl: THCKIN = 891 ± 250 ps.
11. TOD depends on DMUXDelAdjCtrl: TOD = 1820 ± 250 ps. TOD is given for ECL 50Ω/2 pFoutput load.
12. TOD depends on DMUXDelAdjCtrl: TOD = 1717 ± 250 ps. TOD is given for ECL 50Ω/2 pFoutput load.
13. TPD is the number of Clkln clock cycle from selection of Port A to selection of Port H in 1:8 conversion mode, and from selection of Port A to selection of Port D in 1:4 conversion mode. It is the maximum number of Clkln clock cycle, or pipeline delay, that a data has to stay in the DMUX before being sorted out. This maximum delay occurs for the data sent to Port A. For instance, the data sent to Port H goes directly from the input to the Port H, and its pipeline is 0. But even for this data, there is an additional delay due to physical propagation time in the DMUX.
14. TROD and TFOD are given for ECL 50Ω/2 pF output load. In TTL mode, the TROD and TFOD are twice the ones for ECL. (For other termination topology, apply proper derating value 50 ps/pF in ECL, 100 ps/pF in TTL mode.)
15. TDRF depends on DMUXDelAdjCtrl: TDRF = 1856 ± 250 ps. It is given for ECL 50Ω/2 pF output load.
16. TDRF depends on DMUXDelAdjCtrl: TDRF = 1753 ± 250 ps. It is given for ECL 50Ω/2 pF output load.
17. TDRR depends on DMUXDelAdjCtrl: TDRR = 1858 ± 250 ps. It is given for ECL 50Ω/2 pF output load.
18. TDRR depends on DMUXDelAdjCtrl: TDRR = 1725 ± 250 ps. It is given for ECL 50Ω/2 pF output load.
19. TARDR is given for ECL 50Ω/2 pF output load.
20. TSRDR is given for ECL 50Ω/2 pF output load. It is minimum value since RstSync clock is synchronized with Clkln clock.
21. TRDR and TFDR are given for ECL 50Ω/2 pF output load.
22. THBIST depends on the configuration of the DMUX. There must be enough Clkln clock cycles to have all the 512 codes, (see different Timing Diagrams).
23. With transmission line (ZO = 50Ω) and output load R = 50Ω; C = 2 pF.
24. Without output load.
25. With transmission line (ZO = 50Ω) and output load R = 50Ω; C = 2 pF.

Input Clock Timings

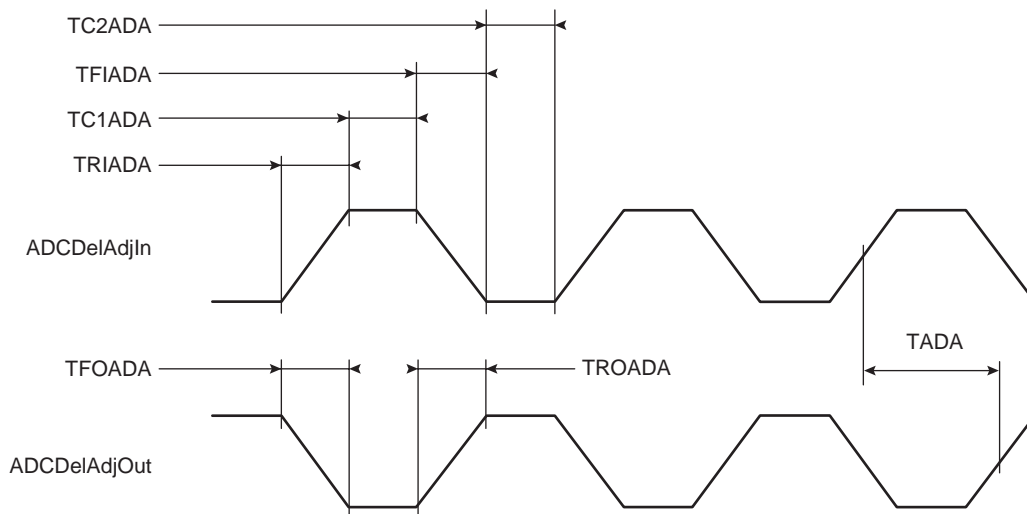**Figure 10.** Input Clock

ClkIn Type = 1
DataReady Mode (DR)

ClkIn Type = 0
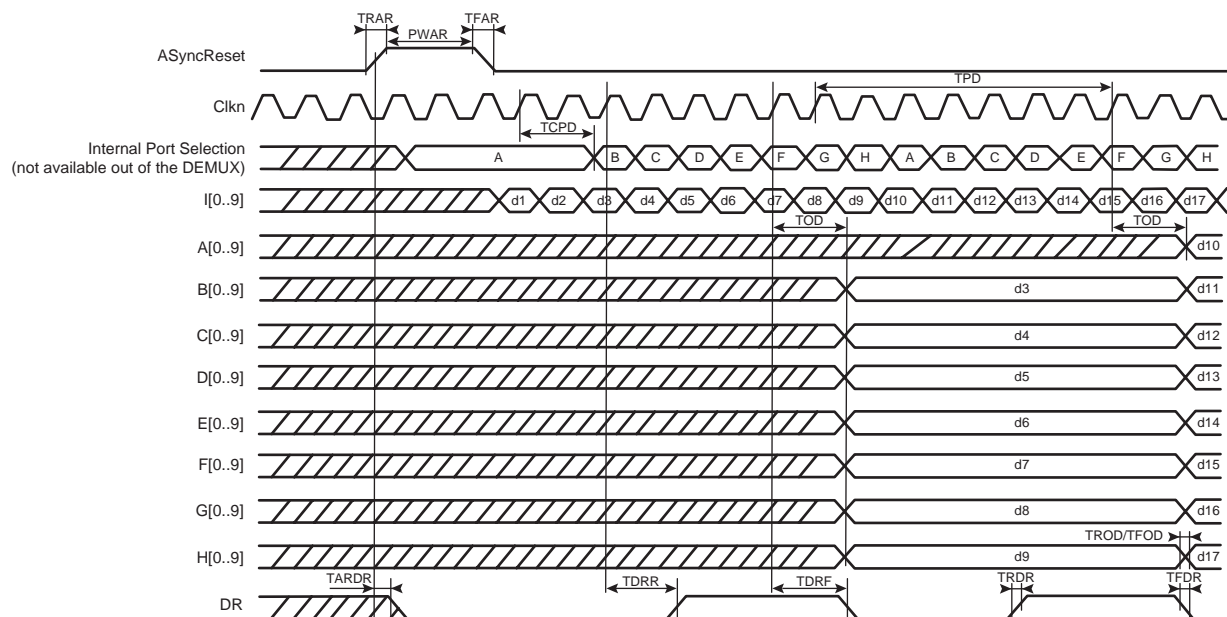DataReady/2 Mode (DR/2)

ADC Delay Adjust Timing Diagram

Figure 11. ADC Delay Adjust Timing Diagram
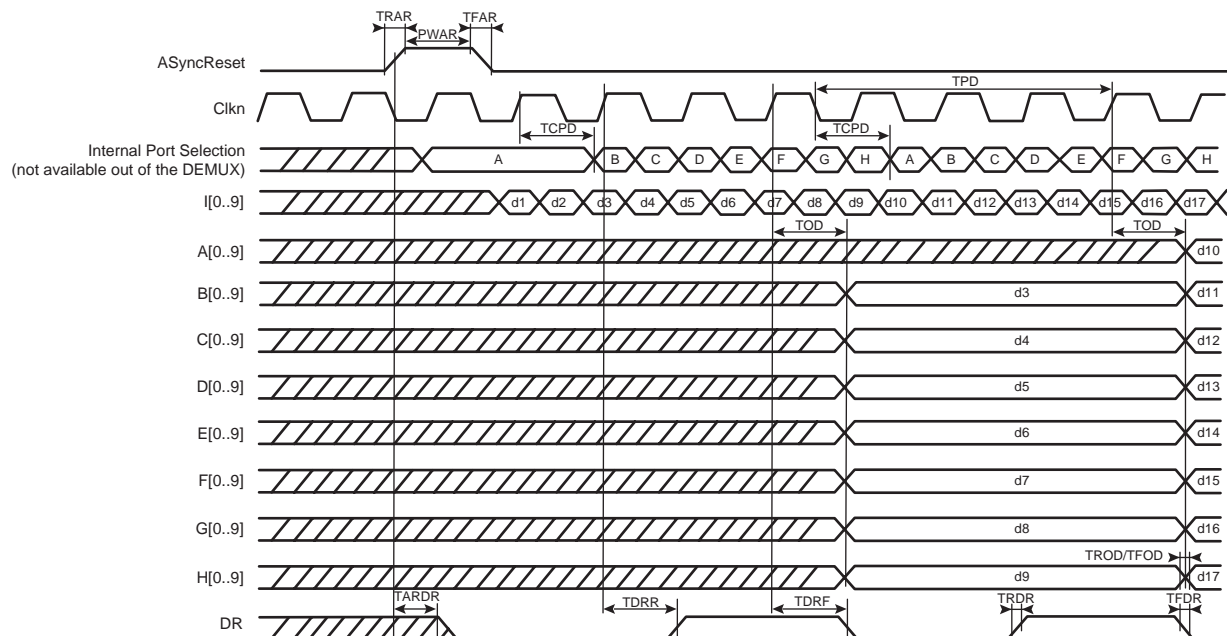
Timing Diagrams with Asynchronous Reset

With a nominal tuning of DMUXDelAdj at a frequency of 2 GHz, d1 and d2 data is lost because of the internal clock's path propagation delay TCPD. TCPD is tuned with DMUXDelAdjCtrl pins to obtain good setup and hold times between ClkIn and the data.

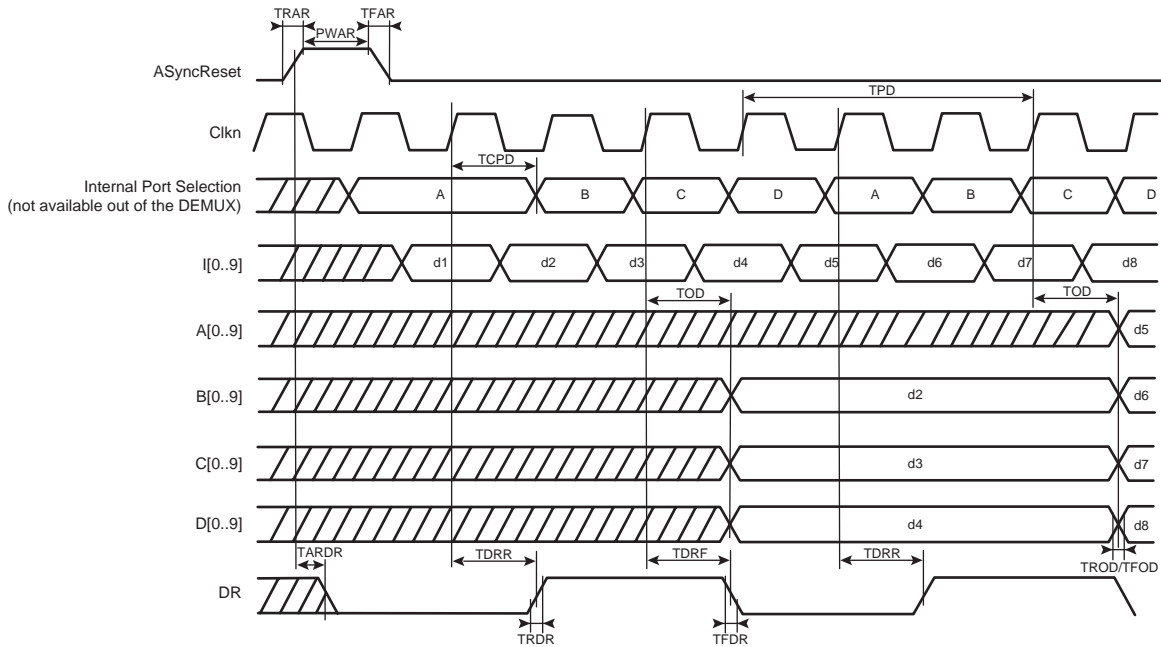**Figure 12.** Start with Asynchronous Rest, 1:8 Ratio, DR Mode

With a nominal tuning of DMUXDelAdj at 2 GHz, d1 and d2 data is lost because of the internal clock's path propagation delay TCPD. TCPD is tuned with DMUXDelAdjCtrl pins to obtain good setup and hold times between ClkIn and the input data. This timing diagram does not change with the opposite phase of ClkIn.

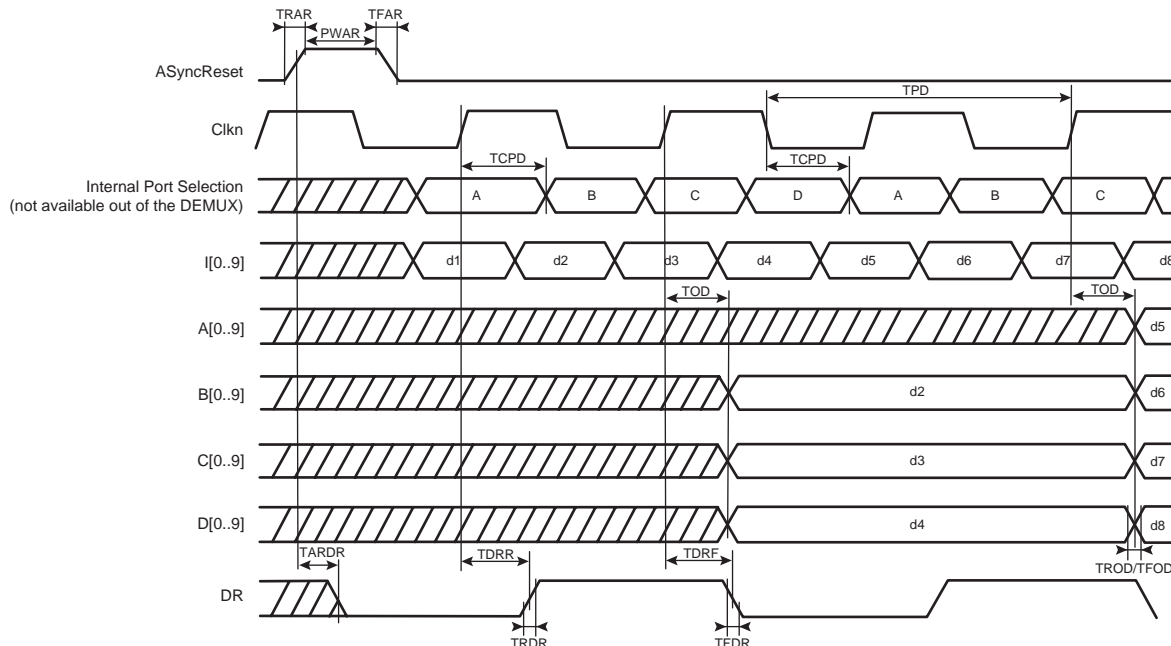**Figure 13.** Start with Asynchronous Rest, 1:8 Ratio, DR/2 Mode

With a nominal tuning of DMUXDelAdj, at 1 GHz (1:4 mode) d1 data is lost because of the internal clock's path propagation delay TCPD. TCPD is tuned with DMUXDelAdjCtrl pins and is used to obtain good setup and hold times between ClkIn and the input data.

Figure 14. Start with Asynchronous Reset, 1:4 Ratio, DR Mode

With a nominal tuning of DMUXDelAdj, at 1 GHz (1:4 mode) d1 data is lost because of the internal clock's path propagation delay TCPD. TCPD is tuned with DMUXDelAdjCtrl pins and is used to obtain good setup and hold times between ClkIn and the input data. This timing diagram does not change with the opposite phase of ClkIn.

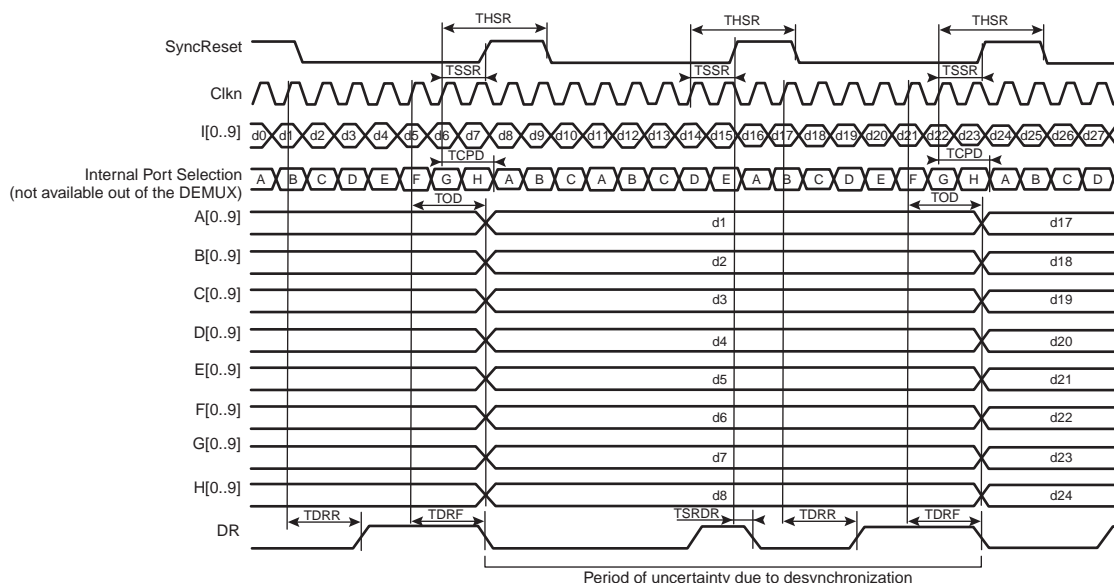**Figure 15.** Start with Asynchronous Reset, 1:4 Ratio, DR/2 Mode

Timing Diagrams with Synchronous Reset

Following is an example of the Synchronous Reset's utility in case of de-synchronization of the DMUX output port selection. The de-synchronization event happens after the selection of Port D.

DMUXDelAdjCtrl value is nominal. TSSR < 0 because of ClkIn's internal propagation delay TCPD. After selection of Port C, instead of selecting Port D, the de-synchronization makes the port selection to restart on Port A. Since Port H was not selected, the data is not output to the ports but the last data (d1 to d8) is latched until the next selection of Port H. d9 to d16 are lost. The synchronous Reset ensures a re-synchronization of the port selection.
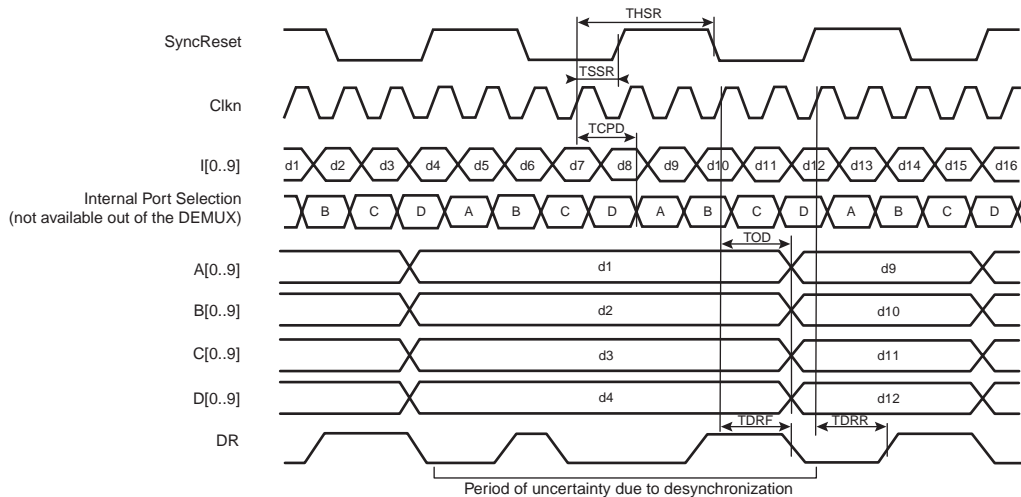
Figure 16. Synchronous Reset, 1:8 Ratio, DR Mode

Example of the Synchronous Reset's utility in case of de-synchronization of the DMUX output port selection. The de-synchronization event happens after the selection of Port D.

DMUXDelAdjCtrl value is nominal. TSSR < 0 because of ClkIn's internal propagation delay TCPD. After selection of Port C, instead of selecting Port D, the de-synchronization makes the port selection to restart on Port A. Since Port H was not selected, the data is not output to the ports but the last data (d1 to d4) is latched until the next selection of Port H. d5 to d8 are lost. The synchronous Reset ensures a re-synchronization of the port selection.

Figure 17. Synchronous Reset, 1:4 Ratio, DR Mode

Example of Synchronous Reset's utility in case of de-synchronization of the DMUX output port selection. The de-synchronization event happens after the selection of Port D.

DMUXDelAdjCtrl value is nominal. TSSR < 0 because of ClkIn's internal propagation delay TCPD. After selection of Port C, instead of selecting Port D, the de-synchronization makes the port selection to restart on Port A. Since Port H was not selected, the data is not output to the ports but the last data (d1 to d8) is latched until the next selection of Port H. d9 to d16 are lost. The synchronous Reset ensures a re-synchronization of the port selection.
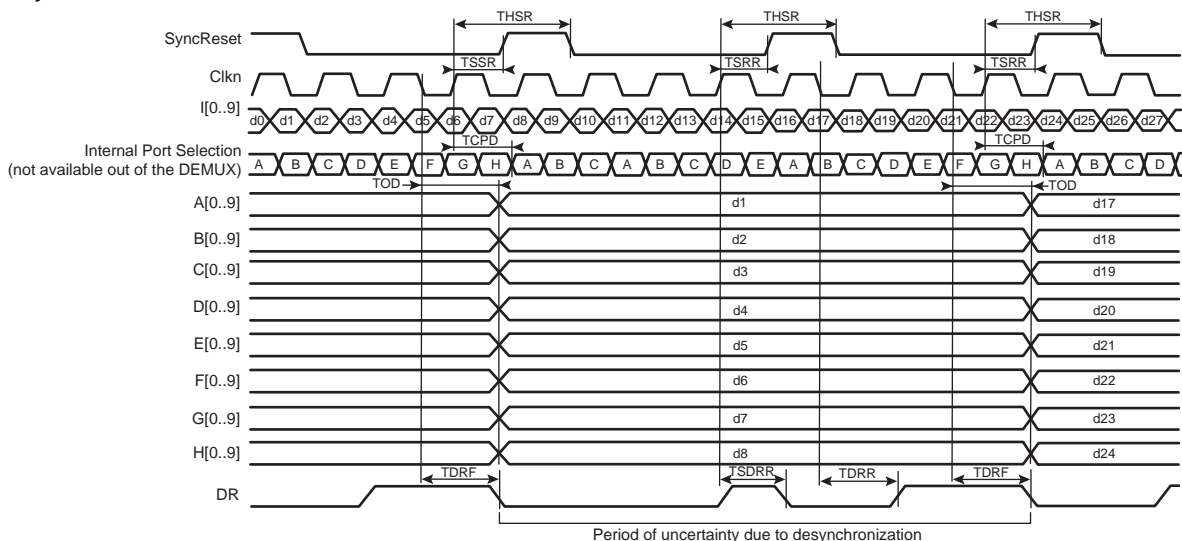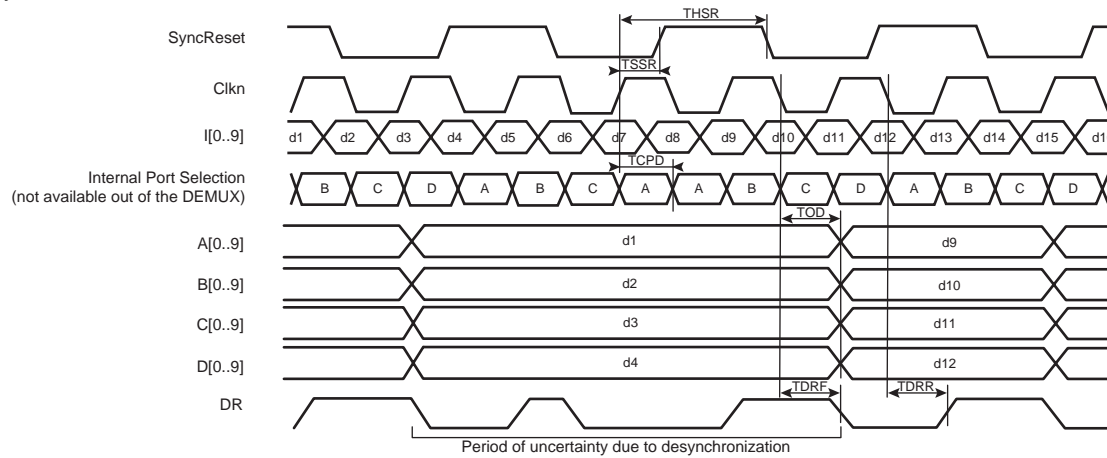
Figure 18. Synchronous Reset, 1:8 ratio, DR/2 Mode

Example of Synchronous Reset's utility in case of de-synchronization of the DMUX output port selection. The de-synchronization event happens after the selection of Port D.

DMUXDelAdjCtrl value is nominal. TSSR < 0 because of ClkIn's internal propagation delay TCPD. After selection of Port C, instead of selecting Port D, the de-synchronization makes the port selection to restart on Port A. Since Port H was not selected, the data is not output to the ports but the last data (d1 to d4) is latched until the next selection of Port H. d5 to d8 are lost. The synchronous Reset ensures a re-synchronization of the port selection.

Figure 19. Synchronous Reset, 1:4 ratio, DR/2 Mode

Note: In case of low clock frequency and start with asynchronous reset, only the first data is lost and the first data to be processed is the second one. This data is output from the DMUX through port B.

Explanation of Test Levels

Table 6. Explanation of Test Levels

Num	Characteristics
1	100% production tested at +25°C.[1]
2	100% production tested at +25°C, and sample tested at specified temperatures.[1]
3	Sample tested only at specified temperatures.
4	Parameter is guaranteed by design and characterization testing (thermal steady-state conditions at specified temperature).
5	Parameter is a typical value only.

Notes: 1. The level 1 and 2 tests are performed at 50 MHz.
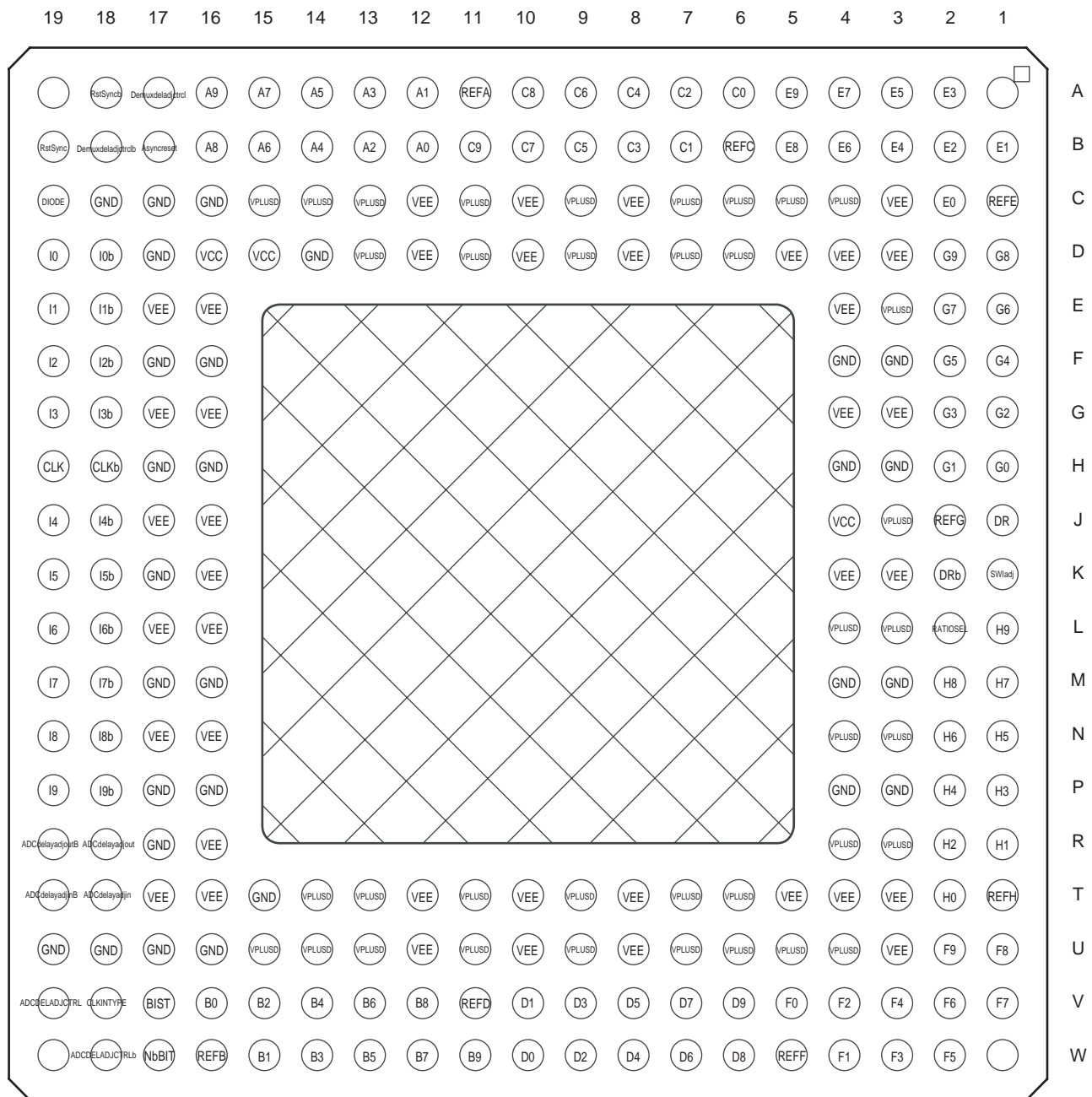2. Only MIN and MAX values are guaranteed (typical values are issuing from characterization results).

Package Description

Pin Description

Table 7. TS81102G0 Pin Description

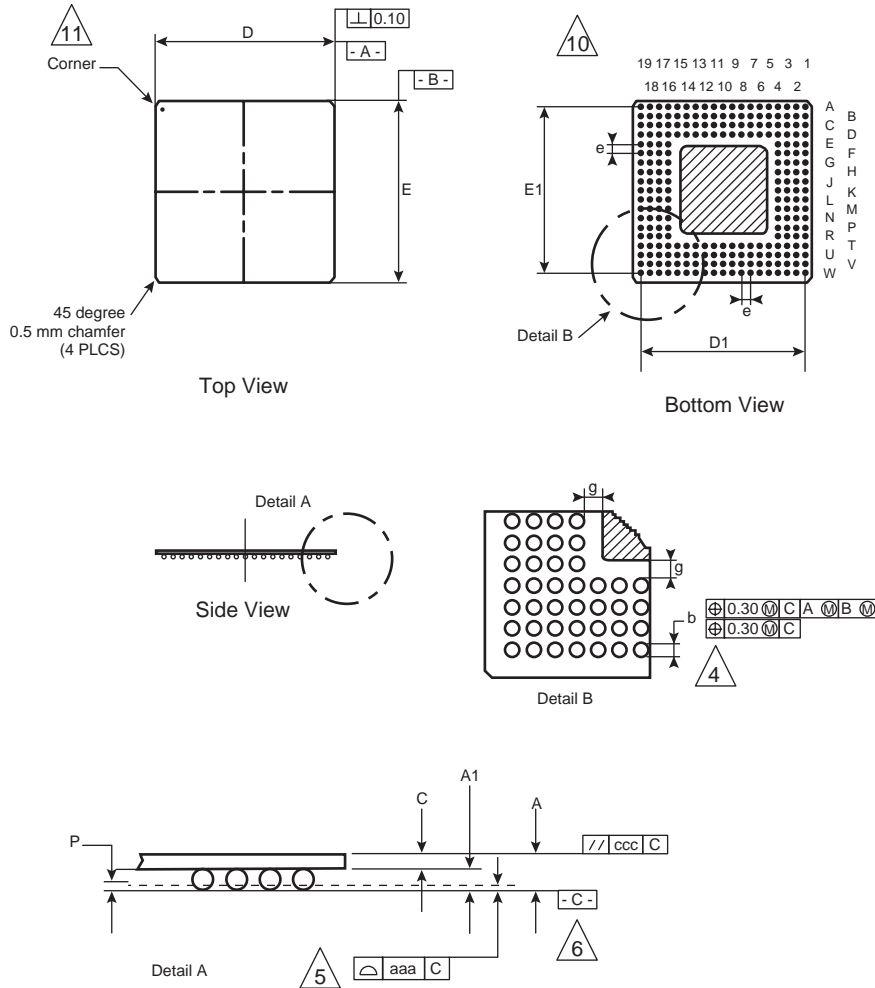| Type	Name	Levels	Comments
Digital Inputs	I[0…9]	Differential ECL	Data input. On-chip 100Ω differential termination resistor.
	ClkIn	Differential ECL	Clock input (Data Ready ADC). On-chip 100Ω differential termination resistor.
Outputs	A[0…9] → H[0…9]	Adjustable Logic Single	Data ready for port A to H. Common mode is adjusted with VplusDOut. Swing is adjusted with SwiAdj. 50Ω termination possible.
	DR	Adjustable Logic Differential	Data ready for channel A to H. Common mode is adjusted with VplusDOut. Swing is adjusted with SwiAdj. 50Ω termination possible.
	RefA → RefH	Adjustable Single	Reference voltage for output channels A to H. Common mode is adjustable with VplusDOut. 50Ω termination possible.
Control Signals	ClkInType	TTL	DataReady or Dataready/2: logic 1: Data Ready.
	RatioSel	TTL	DMUX ratio; logic 1: 1:4
	Bist	TTL	Reset and Switch of built-in Self Test (BIST): logic 0: BIST active.
	SwiAdj	0V ± 0.5V	Swing fine adjustment of output buffers.
	Diode	Analog	Diode for chip temperature measurement.
	NbBit	TTL	Number of bit 8 or 10: logic 1: 10-bit.
Synchronization	AsyncReset	TTL	Asynchronous reset: logic 1: reset on.
	SyncReset	Differential ECL	Synchronous reset: active on rising edge.
	DMUXDelAdjCtrl	Differential analog input of ±0.5V around 0V common mode	Control of the delay line of DataReady input: differential input = -0.5V: delay = 250 ps differential input = 0V: delay = 500 ps differential input = 0.5V: delay = 750 ps
	ADCDelAdjCtrl	Differential analog input of ±0.5V around 0V common mode	Control of the delay line for ADC: differential input = - 0.5V: delay = 250 ps differential input = 0V: delay = 500 ps differential input = 0.5V: delay = 750 ps
	ADCDelAdjIn	Differential ECL	Stand-alone delay adjust input for ADC. Differential termination of 100Ω inside the buffer.
	ADCDelAdjOut	50Ω differential output	Stand-alone delay adjust output for ADC.
Power Supplies	GND	Ground 0V	Common ground.
	V_{EE}	Power -5V	Digital negative power supply.
	$V_{PlusDOut}$	Adjustable power from 0V to +3.3V	Common mode adjustment of output buffers.
	V_{CC}	Power +5V	Digital positive power supply.

TBGA 240 Package – Pinout

Row	Col	Name	Row	Col	Name	Row	Col	Name	Row	Col	Name
A	1	NC	D	4	VEE	K	16	VEE	T	17	VEE
A	2	E3	D	5	VEE	K	17	GND	T	18	ADCDELADJIN
A	3	E5	D	6	VPLUSDOUT	K	18	I5B	T	19	ADCDELADJINB
A	4	E7	D	7	VPLUSDOUT	K	19	I5	U	1	F8
A	5	E9	D	8	VEE	L	1	H9	U	2	F9
A	6	C0	D	9	VPLUSDOUT	L	2	RATIOSEL	U	3	VEE
A	7	C2	D	10	VEE	L	3	VPLUSDOUT	U	4	VPLUSDOUT
A	8	C4	D	11	VPLUSDOUT	L	4	VPLUSDOUT	U	5	VPLUSDOUT
A	9	C6	D	12	VEE	L	16	VEE	U	6	VPLUSDOUT
A	10	C8	D	13	VPLUSDOUT	L	17	VEE	U	7	VPLUSDOUT
A	11	REFA	D	14	GND	L	18	I6B	U	8	VEE
A	12	A1	D	15	VCC	L	19	I6	U	9	VPLUSDOUT
A	13	A3	D	16	VCC	M	1	H7	U	10	VEE
A	14	A5	D	17	GND	M	2	H8	U	11	VPLUSDOUT
A	15	A7	D	18	I0B	M	3	GND	U	12	VEE
A	16	A9	D	19	I0	M	4	GND	U	13	VPLUSDOUT
A	17	DEMUXDELADJCTRL	E	1	G6	M	16	GND	U	14	VPLUSDOUT
A	18	RSTSYNCB	E	2	G7	M	17	GND	U	15	VPLUSDOUT
A	19	NC	E	3	VPLUSDOUT	M	18	I7B	U	16	GND
B	1	E1	E	4	VEE	M	19	I7	U	17	GND
B	2	E2	E	16	VEE	N	1	H5	U	18	GND
B	3	E4	E	17	VEE	N	2	H6	U	19	GND
B	4	E6	E	18	I1B	N	3	VPLUSDOUT	V	1	F7
B	5	E8	E	19	I1	N	4	VPLUSDOUT	V	2	F6
B	6	REFC	F	1	G4	N	16	VEE	V	3	F4
B	7	C1	F	2	G5	N	17	VEE	V	4	F2
B	8	C3	F	3	GND	N	18	I8B	V	5	F0
B	9	C5	F	4	GND	N	19	I8	V	6	D9
B	10	C7	F	16	GND	P	1	H3	V	7	D7
B	11	C9	F	17	GND	P	2	H4	V	8	D5
B	12	A0	F	18	I2B	P	3	GND	V	9	D3
B	13	A2	F	19	I2	P	4	GND	V	10	D1
B	14	A4	G	1	G2	P	16	GND	V	11	REFD
B	15	A6	G	2	G3	P	17	GND	V	12	B8
B	16	A8	G	3	VEE	P	18	I9B	V	13	B6
B	17	ASYNCRESET	G	4	VEE	P	19	I9	V	14	B4
B	18	DEMUXDELADJCTRLB	G	16	VEE	R	1	H1	V	15	B2
B	19	RSTSYNC	G	17	VEE	R	2	H2	V	16	B0
C	1	REFE	G	18	I3B	R	3	VPLUSDOUT	V	17	BIST
C	2	E0	G	19	I3	R	4	VPLUSDOUT	V	18	CLKINTYPE
C	3	VEE	H	1	G0	R	16	VEE	V	19	ADCDELADJCTRL
C	4	VPLUSDOUT	H	2	G1	R	17	GND	W	1	NC
C	5	VPLUSDOUT	H	3	GND	R	18	ADCDELADJOUT	W	2	F5
C	6	VPLUSDOUT	H	4	GND	R	19	ADCDELADJOUTB	W	3	F3
C	7	VPLUSDOUT	H	16	GND	T	1	REFH	W	4	F1
C	8	VEE	H	17	GND	T	2	H0	W	5	REFF
C	9	VPLUSDOUT	H	18	CLKINB	T	3	VEE	W	6	D8
C	10	VEE	H	19	CLKIN	T	4	VEE	W	7	D6
C	11	VPLUSDOUT	J	1	DR	T	5	VEE	W	8	D4
C	12	VEE	J	2	REFG	T	6	VPLUSDOUT	W	9	D2
C	13	VPLUSDOUT	J	3	VPLUSDOUT	T	7	VPLUSDOUT	W	10	D0
C	14	VPLUSDOUT	J	4	VCC	T	8	VEE	W	11	B9
C	15	VPLUSDOUT	J	16	VEE	T	9	VPLUSDOUT	W	12	B7
C	16	GND	J	17	VEE	T	10	VEE	W	13	B5
C	17	GND	J	18	I4B	T	11	VPLUSDOUT	W	14	B3
C	18	GND	J	19	I4	T	12	VEE	W	15	B1
C	19	DIODE	K	1	SWIADJ	T	13	VPLUSDOUT	W	16	REFB
D	1	G8	K	2	DRB	T	14	VPLUSDOUT	W	17	NBBIT
D	2	G9	K	3	VEE	T	15	GND	W	18	ADCDELADJCTRLB
D	3	VEE	K	4	VEE	T	16	VEE	W	19	NC

Figure 20. TBGA 240 Package: Bottom View

	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	
A		RstSyncb	Demuxdeladjctrl	A9	A7	A5	A3	A1	REFA	C8	C6	C4	C2	C0	E9	E7	E5	E3		A
B	RstSync	Demuxdeladjctrlb	Asyncreset	A8	A6	A4	A2	A0	C9	C7	C5	C3	C1	REFC	E8	E6	E4	E2	E1	B
C	DIODE	GND	GND	GND	VPLUSD	VPLUSD	VPLUSD	VEE	VPLUSD	VEE	VPLUSD	VEE	VPLUSD	VPLUSD	VPLUSD	VPLUSD	VEE	E0	REFE	C
D	I0	I0b	GND	VCC	VCC	GND	VPLUSD	VEE	VPLUSD	VEE	VPLUSD	VEE	VPLUSD	VPLUSD	VEE	VEE	VEE	G9	G8	D
E	I1	I1b	VEE	VEE												VEE	VPLUSD	G7	G6	E
F	I2	I2b	GND	GND												GND	GND	G5	G4	F
G	I3	I3b	VEE	VEE												VEE	VEE	G3	G2	G
H	CLK	CLKb	GND	GND												GND	GND	G1	G0	H
J	I4	I4b	VEE	VEE												VCC	VPLUSD	REFG	DR	J
K	I5	I5b	GND	VEE												VEE	VEE	DRb	SWIadj	K
L	I6	I6b	VEE	VEE												VPLUSD	VPLUSD	RATIOSEL	H9	L
M	I7	I7b	GND	GND												GND	GND	H8	H7	M
N	I8	I8b	VEE	VEE												VPLUSD	VPLUSD	H6	H5	N
P	I9	I9b	GND	GND												GND	GND	H4	H3	P
R	ADCdelayadjoutB	ADCdelayadjout	GND	VEE												VPLUSD	VPLUSD	H2	H1	R
T	ADCdelayadjinB	ADCdelayadjin	VEE	VEE	GND	VPLUSD	VPLUSD	VEE	VPLUSD	VEE	VPLUSD	VEE	VPLUSD	VPLUSD	VEE	VEE	VEE	H0	REFH	T
U	GND	GND	GND	GND	VPLUSD	VPLUSD	VPLUSD	VEE	VPLUSD	VEE	VPLUSD	VEE	VPLUSD	VPLUSD	VPLUSD	VPLUSD	VEE	F9	F8	U
V	ADCDELADJCTRL	CLKINTYPE	BIST	B0	B2	B4	B6	B8	REFD	D1	D3	D5	D7	D9	F0	F2	F4	F6	F7	V
W		ADCDELADJCTRLb	NbBIT	REFB	B1	B3	B5	B7	B9	D0	D2	D4	D6	D8	REFF	F1	F3	F5		W

Outline Dimensions

Figure 21. Package Dimension – 240 Tape Ball Grid Array

Dimensional References			
Ref.	Min.	Nom.	Max.
A	1.30	1.50	1.70
A1	0.50	0.60	0.70
D	24.80	25.00	25.20
D1	22.86 (BSC.)		
E	24.80	25.00	25.20
E1	22.86 (BSC.)		
b	0.60	0.75	0.90
c	0.80	0.90	1.00
M	19.00		
N	240.00		
aaa	-	-	0.15
ccc	-	-	0.25
e	1.27 TYP.		
g	0.35	-	-
P	0.15	-	-

Notes: 1. All dimensions are in millimeters.

2. "e" represents the basic solder ball grid pitch.

3. "M" represents the basic solder ball matrix size, and symbol "N" is the maximum allowable number of balls after depopulating.

4. "b" is measured at the maximum solder ball diameter parallel to primary datum $\boxed{- C -}$

5. Dimension "aaa" is measured parallel to primary datum $\boxed{- C -}$

6. Primary datum $\boxed{- C -}$ and seatin plane are defined by the spherical crowns of the solder balls.

7. Package surface shall be black oxide.

8. Cavity depth various with die thickness.

9. Substrate material base is copper.

10. Bilateral tolerance zone is applied to each side of package body.

11. 45 deg. 0.5 mm chamfer corner and white dot for pin 1 identification.

Thermal and Moisture Characteristics

Thermal Resistance from Junction to Case: RTHJC

The Rth from junction to case for the TBGA package is estimated at 1.05°C/W that can be broken down as follows:

- Silicon: 0.1°C/W
- Die attach epoxy: 0.5°C/W (thickness # 50 μm)
- Copper block (back side of the package): 0.1°C/W
- Black Ink: 0.251°C/W.

Thermal Resistance from Junction to Ambient: RTHJA

A pin-fin type heat sink of a size 40 mm x 40 mm x 8 mm can be used to reduce thermal resistance. This heat sink should not be glued to the top of the package as Atmel cannot guarantee the attachment to the board in such a configuration. The heat sink could be clipped or screwed on the board.

With such a heat sink, the Rthj-a is about 6°C/W (if we take 10°C/W for Rth from the junction to air through the package and heat sink in parallel with 15°C/W from the junction to the board through the package body, through balls and through board copper).

Without the heat sink, the Rth junction to air for a package reported on-board can be estimated at 13 to 20°C/W (depending on the board used).

The worst value 20°C/W is given for a 1-layer board (13°C for a 4-layer board).

Thermal Resistance from Junction to Bottom of Balls

The thermal resistance from the junction to the bottom of the balls of the package corresponds to the total thermal resistance to be considered from the silicon's die junction to the interface with a board. This thermal resistance is estimated to be 4.8°C/W max.

The following diagram points out how the previous thermal resistances were calculated for this packaged device.

Figure 22. Thermal Resistance from Junction to Bottom of Balls

DEMUX − Axpproximative Model for 240 TBGA

Assumptions:
Square die 7.0 x 7.0 = 49 mm², 75 μm thick Epoxy/Ag glue, 0.40 mm copper thickness under die,
Sn60Pb40 columns diameter 0.76 mm, 23 x 23 mm TBGA

Typical values (values are in °C/Watt)

Silicon Junction

Silicon Die 49 mm² λ = 0.95Watt/°C — 0.10

Epoxy/Ag glue λ = 0.025Watt/°C — 0.60

Copper base (Top half of thickness) λ = 25Watt/°C — 0.05

1.70   0.25

Copper base — 0.05   1.87   1.43   Tape + glue over balls λ = 0.02Watt/°C

Black ink — 0.25   0.40   0.31   Balls PbSn λ = 0.40Watt/°C

Top of package   2 internal rows (104 balls)   2 external rows (136 balls)

Thermal Resistance Junction to case typical = 0.10 + 0.60 + 0.05 + 0.05 + 0.25 = 1.05°C/W

Thermal Resistance Junction to case Max = 1.40°C/W

Case were all Bottom of Balls are connected to infinite heatsink (values are in °C/Watt)

Silicon Junction — 0.10   0.60   0.05

Reduction →   Reduction →

1.70   0.25   Silicon Junction   2.45   Silicon Junction   3.55

2.47   1.74   2.47   1.99

Infinite heatsink at bottom of balls   Infinite heatsink at bottom of balls   Infinite heatsink at bottom of balls

Thermal Resistance Junction to bottom of balls = 4.8°C/W Max

2105C–BDC–11/03

Temperature Diode Characteristic

The theoretical characteristic of the diode according to the temperature when I = 3 mA is depicted below.

Figure 23. Temperature Diode Characteristic

Vdiode

DiodeT

I = 3 mA
dV/dT = 1.32 mV/°C

Temperature (°C)

Moisture Characteristic

This device is sensitive to moisture (MSL3 according to the JEDEC standard).

The shelf life in a sealed bag is 12 months at < 40°C and < 90% relative humidity (RH).

After this bag is opened, devices that might be subjected to infrared reflow, vapor-phase reflow, or equivalent processing (peak package body temperature 220°C) must be:

• mounted within 168 hours at factory conditions of ≤ 30°C/60% RH, or
• stored at ≤ 20% RH.

The devices require baking before mounting, if the humidity indicator is > 20% when read at 23°C ±5°C.

If baking is required, the devices may be baked for:

• 192 hours at 40°C + 5°C/-0°C and < 5% RH for low temperature device containers, or
• 24 hours at 125°C ± 5°C for high-temperature device containers.

Detailled Cross Section

The following diagram depicts a detailed cross section of the DMUX TBGA package.

Figure 24. TBGA 240: 1/2 Cross Section

In the DMUX package shown above, the die's rear side is attached to the copper heat spreader, so the copper heat spreader is at -5V.

It is necessary to use a heat sink tied to the copper heat speader.

Moreover, there is only a little layer of painting over the copper heat spreader which does not isolate it.

It is therefore recommended to either isolate the heat sink from the other components of the board or to electrically isolate the copper heat spreader from the heat sink. In the latter case, one should use adequate low Rth electrical isolation.

Applying the TS81102G0 DMUX

The TSEV81102G0 DMUX evaluation board is designed to be connected with the TSEV8388G and TSEV83102G0 ADC evaluation boards.

Figure 25. TSEV81102G0 DMUX Evaluation Boards

Please refer to the "ADC and DMUX Application Note" for more information.

ADC to DMUX Connections

The DMUX inputs configuration has been optimized to be connected to the TS8388B ADC.

The die in the TBGA package is up. For the ADC, different types of packages can be used such as CBGA with die up or the CQFP68 down. The DMUX device being completely symmetrical, both ADC packages can be connected to the TBGA package of the DMUX criss-crossing the lines (see Table 8).

Table 8. ADC to DMUX Connections

ADC Digital Outputs CQFP68 Package	DMUX Data Inputs TBGA Package	ADC Digital Outputs CBGA Package	DMUX Data Inputs TBGA Package
D0	I7	D0	I0
D1	I6	D1	I1
D2	I5	D2	I2
D3	I4	D3	I3
D4	I3	D4	I4
D5	I2	D5	I5
D6	I1	D6	I6
D7	I0	D7	I7
–	18 not connected	–	18 not connected
–	19 not connected	–	19 not connected

Note: The connection between the ADC evaluation board and the DMUX evaluation board requires a 4-pin shift to make the D0 pin match either the I7 or I0 pin of the DMUX evaluation board.

TSEV81102G0TP: Device Evaluation Board

General Description

The TSEV81102G0TP DMUX Evaluation Board (EB) is designed to simplify the characterization and the evaluation of the TS81102G0 device (2 Gsps DMUX). The DMUX EB enables testing of all the DMUX functions: Synchronous and Asynchronous reset functions, selection of the DMUX ratio (1:4 or 1:8), selection of the number of bits (8 or 10), output data common mode and swing adjustment, die junction temperature measurements over military temperature range, etc.

The DMUX EB has been designed to enable easy connection to Atme's ADC Evaluation Boards (such as TSEV8388BGL or TSEV83102G0BGL) for an extended functionality evaluation (ADC and DMUX multi-channel applications).

The DMUX EB comes fully assembled and tested, with a TS81102G0 device implemented on the board and a heat sink assembled on the device.

Ordering Information

Table 9. Ordering Information

Part Number	Package	Temperature Range	Screening	Comments
JTS81102G0-1V1A	Die	Ambient	Visual inspection	
TS81102G0CTP	TBGA 240	"C" grade $0°C < Tc; Tj < 90°C$	Standard	
TS81102G0VTP	TBGA 240	"V" grade $-40°C < Tc; Tj < 110°C$	Standard	
TSEV81102G0TPZR3	TBGA 240	Ambient	Prototype	Evaluation board (delivered with heatsink)

Datasheet Status Description

Table 10. Datasheet Status

Datasheet Status		Validity
Objective specification	This datasheet contains target and goal specifications for discussion with customer and application validation.	Before design phase
Target specification	This datasheet contains target or goal specifications for product development.	Valid during the design phase
Preliminary specification α-site	This datasheet contains preliminary data. Additional data may be published later; could include simulation results.	Valid before characterization phase
Preliminary specification β-site	This datasheet contains also characterization results.	Valid before the industrialization phase
Product specification	This datasheet contains final product specification.	Valid for production purposes
Limiting Values		
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.		
Application Information		
Where application information is given, it is advisory and does not form part of the specification.		

Life Support Applications

These products are not designed for use in life-support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Atmel customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Atmel for any damages resulting from such improper use or sale.

Addendum

This section has been added to the description of the device for better understanding of the synchronous reset operation. It puts particular stress on the setup and hold times defined in the switching characteristics table (Table 5), linked with the device performances when used at full speed (2 Gsps).

Synchronous Reset Operation

It first describes the operation of the synchronous reset in case the DMUX is used in DR mode and then when used in the DR/2 mode.

As a reminder, the synchronous reset has to be a signal frequency of Fs/8N in 1:8 ratio or Fs/4N in 1:4 ratio, where N is an integer.

The effect of the synchronous reset is to ensure that at each new port selection cycle, the first port to be selected is port A. The synchronous reset ensures the internal cyclic synchronization of the device during operation. It is also highly recommended in the case of multichannel applications using 2 synchronized DMUXs.

SETUP and HOLD Timings

The setup and hold times for the reset are defined as follows:

- SETUP from SynchReset to Clkin:

Required delay between the rising edge of the reset and the rising edge of the clock to ensure that the reset will be taken into account at the next clock edge. If the reset rising edge occurs at less than this setup time, it will be taken into account only at the second next rising edge of the clock.

A margin of ± 100ps has to be added to this setup time to compensate for the delays from the drivers and lines.

- HOLD from Clkin and SynchReset:

Minimum duration of the reset signal at a high level to be taken into account by the DMUX. This means that the reset signal has to satisfy 2 requirements: a frequency of Fs/8N or Fs/4N (N is an integer) depending on the ratio and a duty cycle such that it is high during at least the hold time.

Operation in DR Mode

In DR mode, the DMUX input clock can run at up to 2 GHz in 1:8 ratio or 1 GHz in 1:4 ratio. Both cases are described in the following timing diagrams.

Figure 26. Synchronous Reset Operation in DR Mode, 1:4 ratio, 1GHz (Full Speed) – Principle of Operation
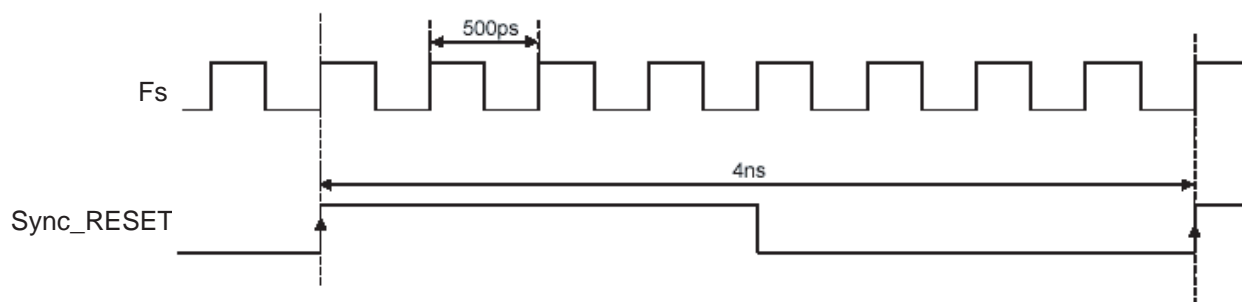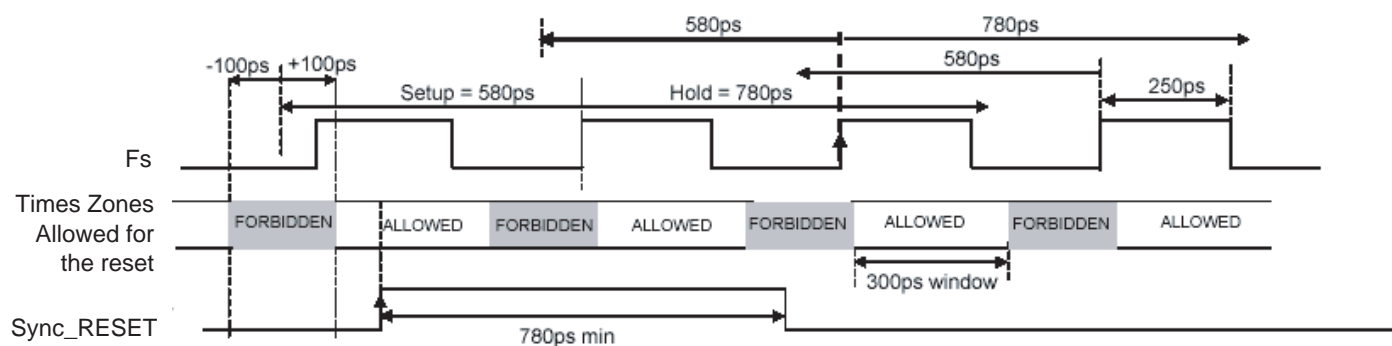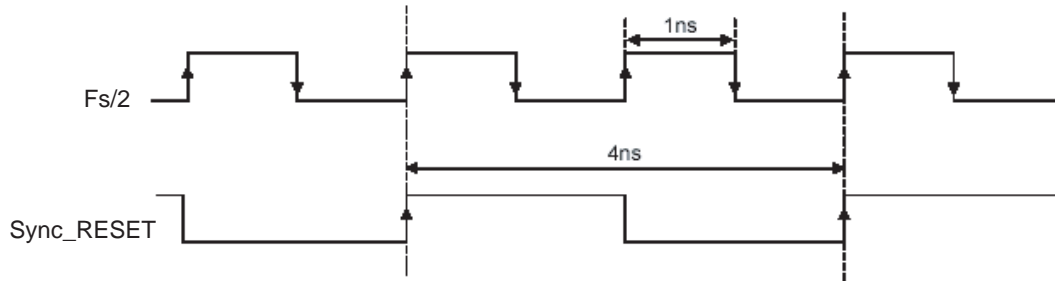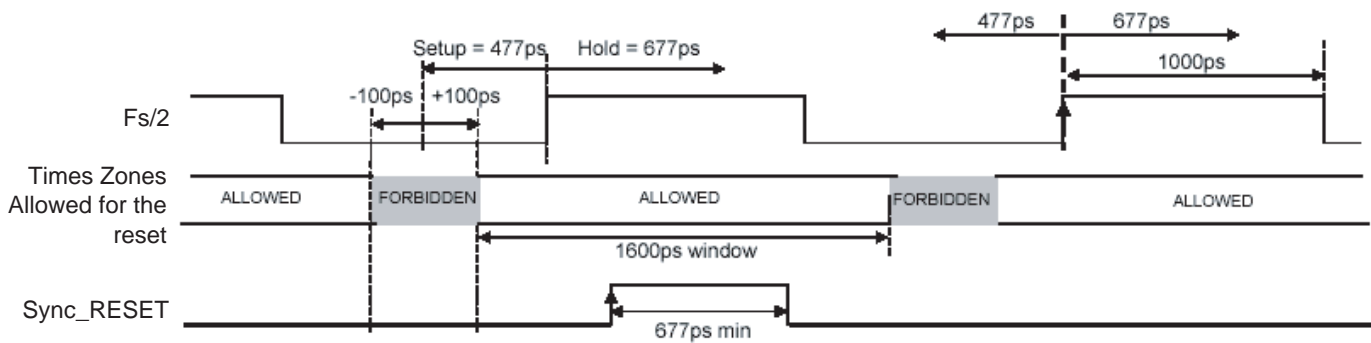
Figure 27. Synchronous Reset Operation in DR Mode, 1:4 ratio, 1GHz (Full Speed) – TIMINGS

Note: The clock edge to which the reset applies is the one identified by the arrow.

If the reset rising edge had occurred in the second allowed window, the reset would have been effective on the third clock rising edge (not represented, on the right of the edge represented with the arrow).

Figure 28. Synchronous Reset Operation in DR Mode, 1:8 ratio, 2 GHz (Full-speed) – Principle of Operation
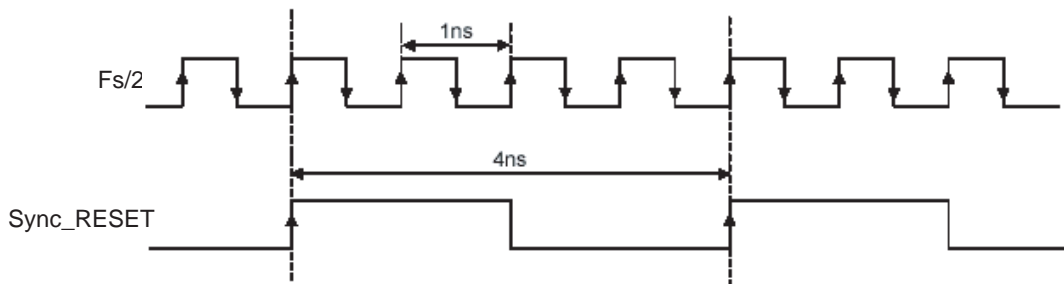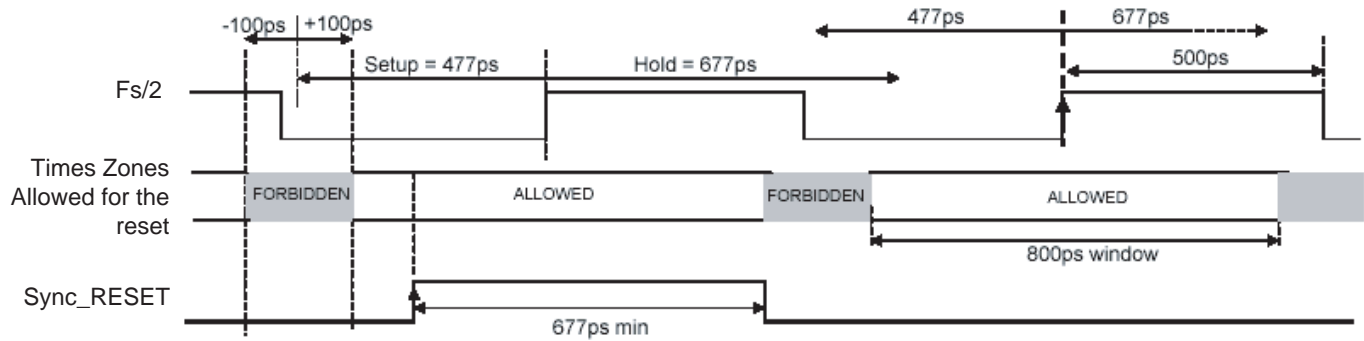

Figure 29. Synchronous Reset Operation in DR Mode, 1:8 ratio, 2 GHz (Full-speed) – Timings

Note: The clock edge to which the reset applies is the one identified by the arrow.

If the reset rising edge had occurred in the second allowed window, the reset would have been effective on the fourth clock rising edge (last clock rising edge, on the right of the edge represented with the arrow).

This case is the most critical one with only a 300 ps window for the reset.

Operation in DR/2 Mode

In DR/2 mode, the DMUX input clock can run at up to 1 GHz in 1:8 ratio or 500 MHz in 1:4 ratio, since the DR/2 clock from the ADC is half the sampling frequency.

Both cases are described in the following timing diagrams.

Figure 30. Synchronous Reset Operation in DR/2 Mode, 1:4 ratio, 500MHz (Full Speed) – Principle of Operation

Figure 31. Synchronous Reset Operation in DR/2 Mode, 1:4 ratio, 500 MHz (Full-speed) – Timings

Note: The clock edge to which the reset applies is the one identified by the arrow.

If the reset rising edge had occurred in the first allowed window (on the left), the reset would have been effective on the first represented clock rising edge (first clock rising edge of the schematic, on the left of the edge represented with the arrow).

Figure 32. Synchronous Reset Operation in DR/2 Mode, 1:8 ratio, 1GHz (Full Speed) – Principle of Operation

Figure 33. Synchronous Reset Operation in DR/2 Mode, 1:8 ratio, 1GHz (Full-speed) – Timings

Note: The clock edge to which the reset applies is the one identified by the arrow.

If the reset rising edge had occurred in the second allowed window, the reset would have been effective on the fourth clock rising edge (not represented, on the right of the edge represented with the arrow).

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